

# High Performance, Tripple-Ouput, Auto-Tracking Combo Controller

# FEATURES

- Provide Triple Accurate Regulated Voltages
- Optimized Voltage-Mode PWM Control
- Dual N-Channel MOSFET Synchronous Drivers
- Fast Transient Response
- Adjustable Over Current Protection using R<sub>DS(on)</sub>. No External Current Sense Resistor Required.
- Programmable Softstart Function
- 200KHz Free-Running Oscillator
- Robust Outputs Auto-Tracking Characteristics
- Sink and Source Capabilities with External Circuit

# APPLICATIONS

- Advanced PC Mboards
- Information PCs
- Servers and Workstations
- Internet Appliances
- PC Add-On Cards
- DDR Termination.

## GENERAL DESCRIPTION

The AIC1340 combines a synchronous voltage mode PWM controller with a low dropout linear regulator and a linear controller as well as the monitoring and protection functions in this chip. The PWM controller regulates the output voltage with a synchronous rectified step-down converter. The built-in N-Channel MOSFET drivers also help to simplify the design of step-down converter. It is able to power CPUs, GPUs, memories, and chipsets. The PWM controller features over current protection using  $R_{DS(on)}$ . It improves efficiency and saves cost, as there is no expensive current sense resistor required.

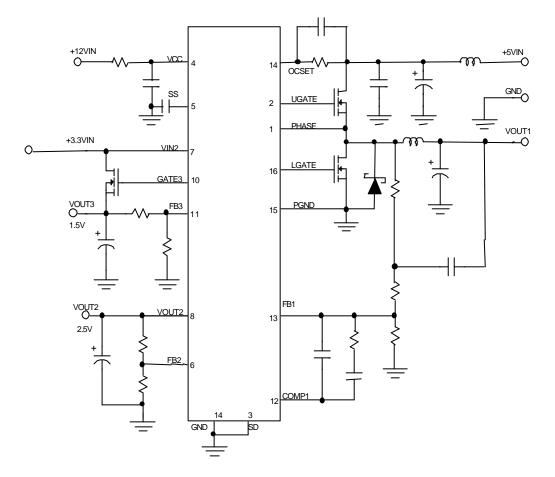
The built-in adjustable linear controller drives an external MOSFET to form a linear regulator that regulates power for system I/O. The built-in adjustable low dropout linear regulator can supply current up to 500mA for supplying another system I/O. Output voltage of both linear regulators can also be adjusted by means of the external resistor divider. Both linear regulators feature current limit. With higher load current required from the low dropout linear regulator, the AIC1341 is recommended.

The Shutdown function is also provided for disable the combo controller.

DS-1340-00 May 24, 01

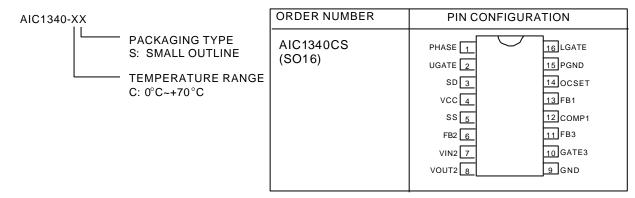


# **TYPICAL APPLICATION CIRCUIT**



**Typical Triple-Output Application** 

# **ORDERING INFORMATION**





## **ABSOLUTE MAXIMUM RATING**

#### **Absolute Maximum Ratings**

| Supply Voltage (VCC)         |                          |
|------------------------------|--------------------------|
| UGATE                        | GND - 0.3V to VCC + 0.3V |
| LGATE                        | GND - 0.3V to VCC + 0.3V |
| Input Output and I/O Voltage |                          |

#### **Operating Conditions**

| Ambient Temperature Range              | 0° C to 85°C |
|--|--------------|
| Maximum Operating Junction Temperature | 100°C        |
| Supply Voltage, VCC                    | 15V±10%      |

#### **Thermal Information**

| Thermal Resistance θJA (°C/W)                  |               |
|--|---------------|
| SOIC Package                                   | 100°C/W       |
| Maximum Junction Temperature (Plastic Package) | 150°C         |
| Maximum Storage Temperature Range              | 65°C to 150°C |
| Maximum Lead Temperature (Soldering 10s)       |               |

### **TEST CIRCUIT**

Refer to APPLICATION CIRCUIT.



# ELECTRICAL CHARACTERISTICS (V<sub>cc</sub>=12V, T<sub>J</sub>=25°C, Unless otherwise specified)

| PARAMETER                                  | TEST CONDITIONS                    | SYMBOL              | MIN.  | TYP.  | MAX.  | UNIT      |
|--|------------------------------------|---------------------|-------|-------|-------|-----------|
| VCC SUPPLY CURRENT                         | VCC SUPPLY CURRENT                 |                     |       |       |       |           |
| Supply Current                             | UGATE, LGATE, GATE3 and VOUT2 open | l <sub>cc</sub>     |       | 1.8   | 3     | mA        |
| POWER ON RESET                             |                                    |                     | -     | -     |       |           |
| Rising VCC Threshold                       | V <sub>OCSET</sub> =4.5V           | $VCC_{THR}$         | 8.6   | 9.5   | 10.4  | V         |
| Falling VCC Threshold                      | V <sub>OCSET</sub> =4.5V           | VCC <sub>THF</sub>  | 8.2   | 9.2   | 10.2  | V         |
| Rising VIN2 Under-Voltage<br>Threshold     |                                    | VIN2 <sub>THR</sub> | 2.5   | 2.6   | 2.7   | V         |
| VIN2 Under-Voltage Hystere-<br>sis         |                                    | VIN2 <sub>HYS</sub> |       | 130   |       | mV        |
| Rising $V_{\text{OCSET1}}$ Threshold       |                                    | V <sub>OCSETH</sub> |       | 1.3   |       | V         |
| OSCILLATOR                                 |                                    |                     | -     | -     |       |           |
| Free Running Frequency                     |                                    | F                   | 170   | 200   | 230   | KHz       |
| Ramp. Amplitude                            |                                    | $\Delta V_{OSC}$    |       | 1.3   |       | $V_{P-P}$ |
| REFERENCE                                  |                                    |                     |       |       |       |           |
| FB2 Reference Voltage                      |                                    | $V_{REF2}$          | 1.240 | 1.265 | 1.290 | V         |
| FB3 Reference Voltage                      |                                    | $V_{REF3}$          | 1.250 | 1.275 | 1.300 | V         |
| LINEAR REGULATOR                           |                                    |                     |       |       |       |           |
| Regulation                                 | 10mA <i<sub>OUT2&lt;150mA</i<sub>  |                     | -1    |       | +1    | %         |
| Under-Voltage Level                        | FB2 falling                        | $FB2_{UV}$          |       | 70    | 82    | %         |
| Over-Current Protection                    |                                    |                     | 430   | 570   |       | mA        |
| Over-Current Protection<br>During Start-up |                                    |                     |       | 750   |       | mA        |
| LINEAR CONTROLLER                          |                                    |                     |       |       |       |           |
| Regulation                                 | 0 < I <sub>GATE3</sub> < 10mA      |                     | -2.5  |       | +2.5  | %         |
| Under-Voltage Level                        | FB3 falling                        | FB3 <sub>UV</sub>   |       | 70    | 80    | %         |



## **ELECTRICAL CHARACTERISTICS** (Continued)

| PARAMETER                             | TEST CONDITIONS                  | SYMBOL             | MIN. | TYP. | MAX. | UNIT |
|---------------------------------------|----------------------------------|--------------------|------|------|------|------|
| PWM CONTROLLER ERRO                   | PWM CONTROLLER ERROR AMPLIFIER   |                    |      |      |      |      |
| DC GAIN                               |                                  |                    |      | 76   |      | dB   |
| Gain Bandwidth Product                |                                  | GBWP               |      | 11   |      | MHz  |
| Slew Rate                             | COMP1=10pF                       | SR                 |      | 6    |      | V/µS |
| PWM CONTROLLER GATE DRIVER            |                                  |                    |      |      |      |      |
| Upper Drive Source                    | VCC=12V, V <sub>UGATE</sub> =11V | $R_{UGH}$          |      | 5.2  | 6.5  | Ω    |
| Upper Drive Sink                      | VCC=12V, V <sub>UGATE</sub> =1V  | $R_{UGL}$          |      | 3.3  | 5    | Ω    |
| Lower Drive Source                    | VCC=12V, V <sub>LGATE</sub> =11V | $R_{LGH}$          |      | 4.1  | 6    | Ω    |
| Lower Drive Sink                      | VCC=12V, V <sub>LGATE</sub> =1V  | $R_{LGL}$          |      | 3    | 5    | Ω    |
| PROTECTION                            |                                  |                    |      |      |      |      |
| OCSET Current Source                  | $V_{OCSET}$ =4.5 $V_{DC}$        | I <sub>OCSET</sub> | 170  | 200  | 230  | μA   |
| Soft-Start Current                    |                                  | I <sub>SS</sub>    |      | 11   |      | μA   |
| Chip Shutdown Soft Start<br>Threshold |                                  |                    |      |      | 1.0  | V    |

#### **PIN DESCRIPTIONS**

- Pin 1: PHASE: Over-current detection pin. Connect the PHASE pin to source of the external high-side N-MOSFET. This pin detects the voltage drop across the high-side N-MOSFET RDS(ON) for overcurrent protection.
- Pin 2: UGATE: External high-side N-MOSFET gate drive pin. Connect UGATE to gate of the external high-side N-MOSFET.
- Pin 3: SD: To shut down the system, active high or floating.
- Pin 4: VCC: The chip power supply pin. It also

provides the gate bias charge for all the MOSFETs controlled by the IC. Recommended supply voltage is 12V.

Pin 5:SS:Soft-start pin. Connect a capaci-<br/>tor from this pin to ground. This<br/>capacitor, along with an internal<br/>10μA (typically) current source,<br/>sets the soft-start interval of the<br/>converter.<br/>Pulling this pin low will shut down

the IC.

Pin 6: FB2: Connect this pin to a resistor dvider to set the linear regulator output voltage.

# AIC1340



Pin 7: VIN2: This pin supplies power to the internal regulator. Connect this pin to a suitable 3.3V source.

> Additionally, this pin is used to monitor the 3.3V supply. If, following a start-up cycle, the voltage drops below 2.6V (typically), the chip shuts down. A new softstart cycle is initiated upon return of the 3.3V supply above the under-voltage threshold.

- Pin 8: VOUT2: Output of the linear regulator. Supplies current up to 500mA.
- Pin 9: GND: Signal GND for IC. All voltage levels are measured with respect to this pin.
- Pin 10: GATE3: Linear Controller output drive pin. This pin can drive either a Darlington NPN transistor or a Nchannel MOSFET.
- Pin 11: FB3 Negative feedback pin for the linear controller error amplifier connect this pin to a resistor dvider to set the linear controller output voltage.

Pin 12: COMP1 External compensation pin. This

pin is connected to error amplifier output and PWM comparator. An RC network is connected to FB1 in to compensate the voltage control feedback loop of the converter.

- Pin 13: FB1 The error amplifier inverting input pin. the FB1 pin and COMP1 pin are used to compensate the voltage-control feedback loop.
- Pin 14: OCSET: Current limit sense pin. Connect a resistor R<sub>OCSET</sub> from this pin to the drain of the external high-side N-MOSFET. R<sub>OCSET</sub>, an internal 200µA current source (I<sub>OCSET</sub>), and the upper N-MOSFET onresistance (R<sub>DS(ON)</sub>) set the overcurrent trip point according to the following equation:

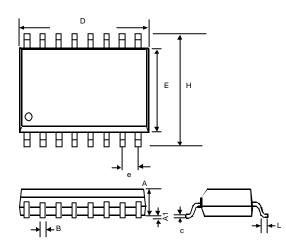
$$I_{PEAK} = \frac{I_{OCSET} \times R_{OCSET}}{R_{DS(ON)}}$$

- Pin 15: PGND: Driver power GND pin. PGND should be connected to a low impedance ground plane in close to lower N-MOSFET source.
- Pin 16: LGATE: Lower N-MOSFET gate drive pin.



# PACKAGE DIMENSIONS

• 16 LEAD PLASTIC SO (300 mil) (unit: mm)



| SYMBOL | MIN       | MAX   |  |
|--------|-----------|-------|--|
| А      | 2.35      | 2.65  |  |
| A1     | 0.10      | 0.30  |  |
| В      | 0.33      | 0.51  |  |
| С      | 0.23      | 0.32  |  |
| D      | 10.10     | 10.50 |  |
| E      | 7.40      | 7.60  |  |
| е      | 1.27(TYP) |       |  |
| Н      | 10.00     | 10.65 |  |
| L      | 0.40      | 1.27  |  |